FEATURES

• 131,072 × 8 bit organization

Access time: 200 ns (MAX.)

• Power consumption:

Operating: 550 mW (MAX.)

- Programmable OE/OE
- Fully static operation
- TTL compatible I/O
- Three-state outputs
- Single +5 V power supply
- Package:
 28-pin, 600-mil DIP
- Mask ROM specific pinout

DESCRIPTION

The LH231000B is a mask programmable ROM organized as $131,072 \times 8$ bits. It is fabricated using silicon-gate NMOS process technology.

PIN CONNECTIONS

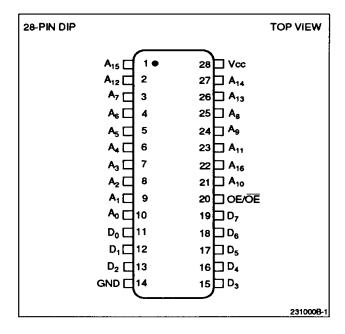


Figure 1. Pin Connections for DIP Package

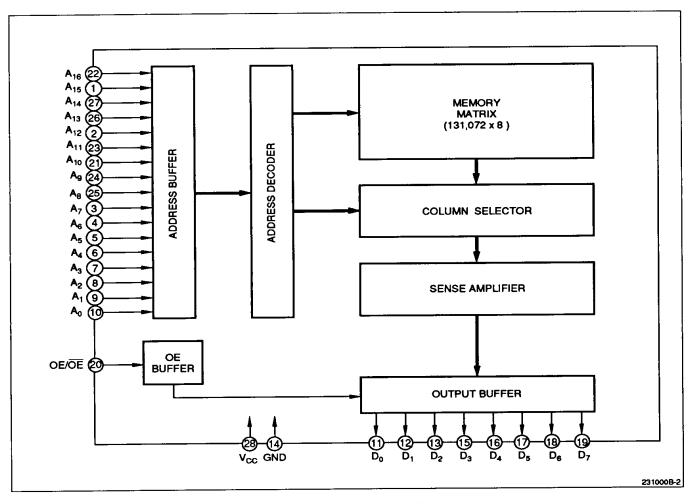


Figure 2. LH231000B Block Diagram

PIN DESCRIPTION

SIGNAL	PIN NAME	NOTE
A ₀ - A ₁₆	Address input	
D ₀ - D ₇	Data output	
CE/OE/OE	Chip enable or Output enable input	1

SIGNAL	PIN NAME	NOTE
Vcc	Power supply (+5 V)	
GND	Ground	

NOTE:

1. The CE/OE/OE function is mask programmable.

TRUTH TABLE

OE/OE	MODE	D ₀ - D ₇	SUPPLY CURRENT
L/H	Non selected	High-Z	Operating (Icc)
H/L	Selected	Dout	Operating (Icc)

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT	NOTE
Supply voltage	Vcc	-0.3 to +7.0	٧	
Input voltage	VIN	-0.3 to +7.0	V	1
Output voltage	Vout	-0.3 to +7.0	٧	
Operating temperature	Topr	0 to +70	°C	
Storage temperature	Tstg	-55 to +150	°C	

RECOMMENDED OPERATING CONDITIONS ($T_A = 0 \text{ to } +70^{\circ}\text{C}$)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply voltage	Vcc	4.5	5	5.5	V

DC CHARACTERISTICS ($V_{CC} = 5 \text{ V} \pm 10\%$, $T_A = 0 \text{ to } +70^{\circ}\text{C}$)

PARAMETER	ì	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	NOTE
Input "Low" voltage		VIL		-0.3		0.8	V	
Input "High" voltage		ViH		2.2		Vcc +0.3	V	
Output "Low" voltage		Vol	I _{OL} = 1.6 mA			0.4	٧	Ī
Output "High" voltage		Vон	loн = -400 μA	2.4			V	
Input leakage current		 Lı	VIN = 0 to VCC			10	μА	
Output leakage current		ILO	Vout = 0 to Vcc			10	μА	1
Current consumption	Operating	lcc	tRC = tRC (MIN.)			100	mA	2

NOTES:

- 1. $\overline{OE} = V_{iH}$ or $OE = V_{iL}$
- 2. VIN = ViH/VIL, outputs open

AC CHARACTERISTICS (V_{CC} = 5 V \pm 10%, T_A = 0 to +70°C)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Read cycle time	tac	200			ns	
Access time	taa			200	ns	
Output enable time	toe			80	ns	
Output floating time	tonz			80	ns	1
Ouput hold time	toH	10			ns	

NOTE:

1. This is the time required for the output to become high-impedance.

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^{1.} The maximum applicable voltage on any pin with respect to GND.

AC TEST CONDITIONS

PARAMETER	RATING
Input voltage amplitude	0.6 V to 2.4 V
Input rise/fall time	10 ns
Input reference level	1.5 V
Output reference level	0.8 V and 2.2 V
Output load condition	1TTL +100 pF

CAPACITANCE (V_{CC} = 5 V \pm 10%, f = 1MHz, T_A = 25°C)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Input capacitance	Cin			8	pF
Output capacitance	Соит			12	рF

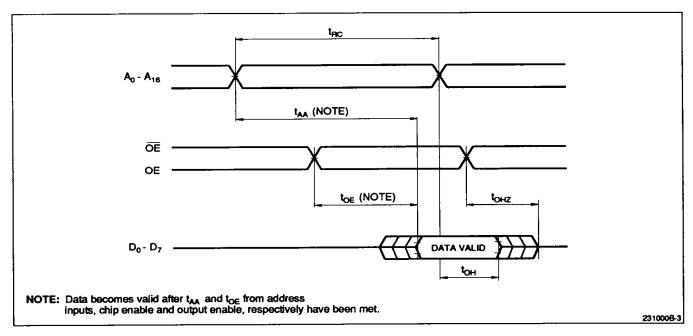
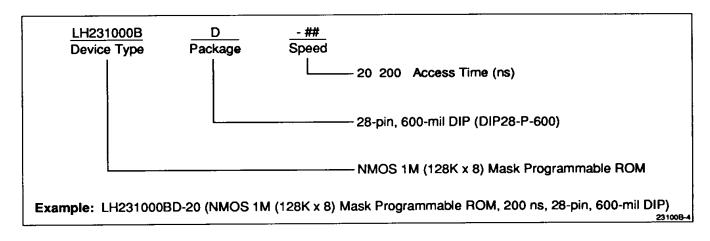


Figure 3. Timing Diagram

ORDERING INFORMATION



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